NSN 5961-01-282-0068

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-282-0068 **Inclosure Material:** Metal **Overall Length:** 92.0 millimeters **Overall Height:** 20.0 millimeters **Overall Width:** 30.0 millimeters **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 300.0 nonrepetitive peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 140.00 amperes forward current, total rms horsepower metric all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 3 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: